

Supporting information

Simple and Efficient Non-doped Deep-Blue and White Organic Light-Emitting Diode Based on Hybridized Local and Charge Transfer (HLCT) Materials

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Section 1

All OLEDs were fabricated on pre-patterned indium tin oxide (ITO) glass substrates with a sheet resistance of $15 \Omega \text{ sq}^{-1}$. ITO-coated glass substrates were cleaned by ultrasonic cleaning in deionized water, acetone and isopropyl alcohol for 20 min in order, then treated with ultraviolet-ozone for 15 min. After this, the ITO substrates were leaded into a deposition chamber, and the OLEDs were fabricated through a vacuum evaporation deposition process under a pressure below 5×10^{-4} Pa. The deposition rates and film thicknesses were monitored by calibrated crystal quartz sensors. The deposition rates for the organic materials, LiF, MoO₃ and Al were 1~2, 0.3, 0.5, and 3~6 \AA s^{-1} , respectively, in particular, the evaporation rate of Ph-UEMs is about 0.1 \AA s^{-1} . All the devices had an active emissive area of 3 mm×3 mm, which are defined by the overlap between the ITO anode and Al cathode. The current density-voltage-luminance (J-V-L) characteristics were performed simultaneously by using a computer-controlled source meter (Keithley 2400) integrated with a BM-7A luminance meter test system. The EL spectra were recorded by a PR655 spectrometer. The EQE was calculated from the current density-voltage-luminance curves and EL spectral data.

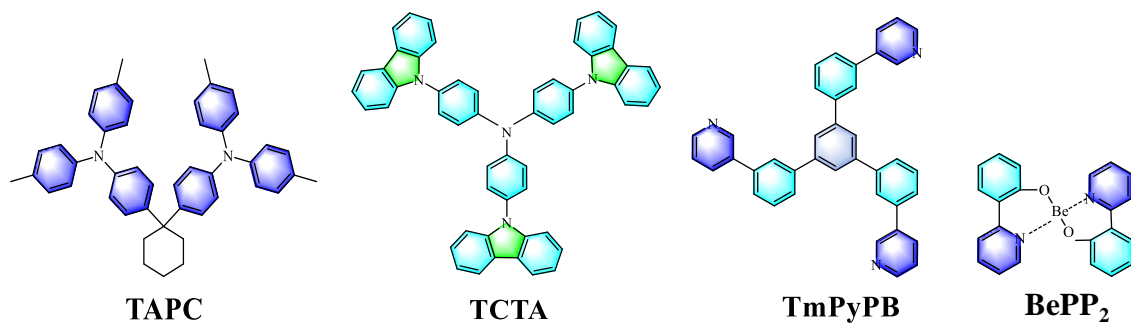


Figure S1. Molecular structures for all organic functional materials used in this work.

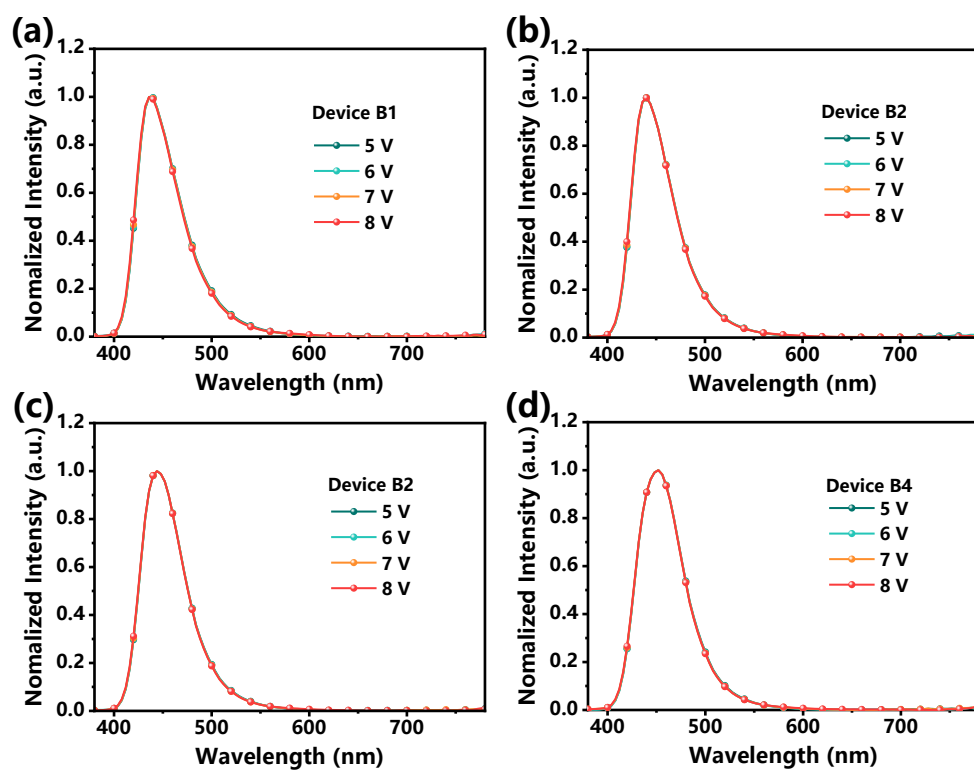


Figure S2. Normalized EL spectra for non-doped blue devices B1-B4 at different driving voltages from 5 V to 8

V.

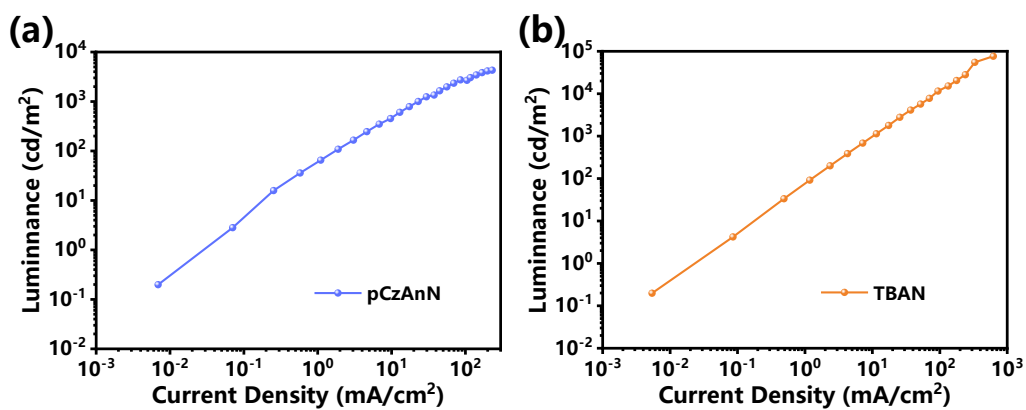


Figure S3. Linear curves of current density-luminance for pCzAnN and TBAN.

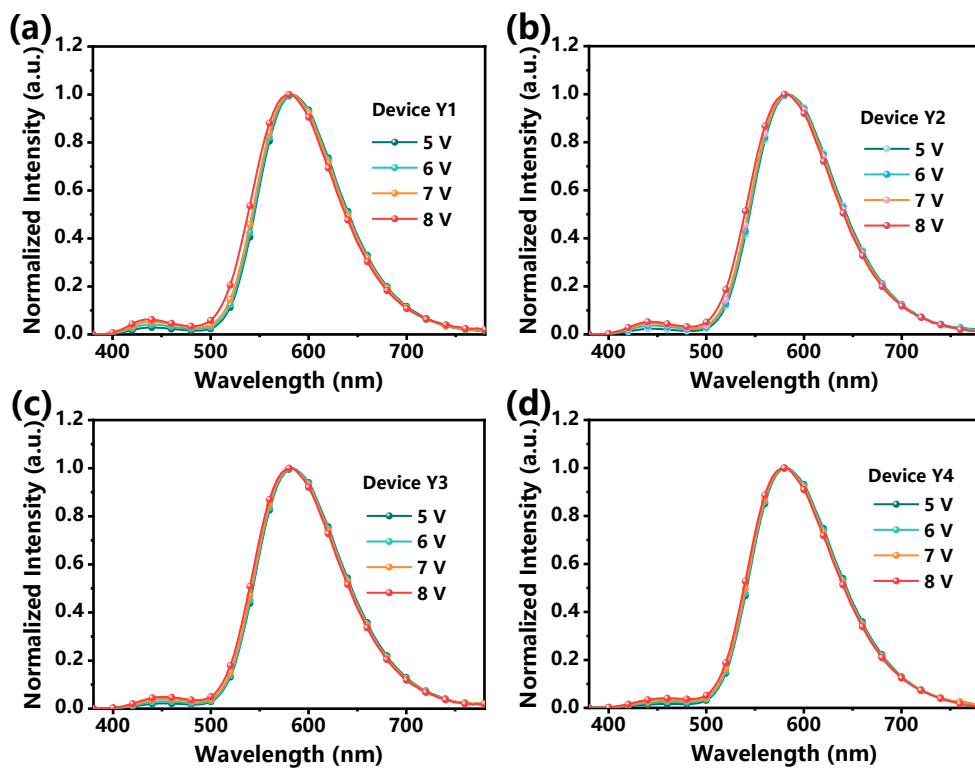


Figure S4. Normalized EL spectra for yellow devices Y1-Y4 at different driving voltages from 5 V to 8 V.

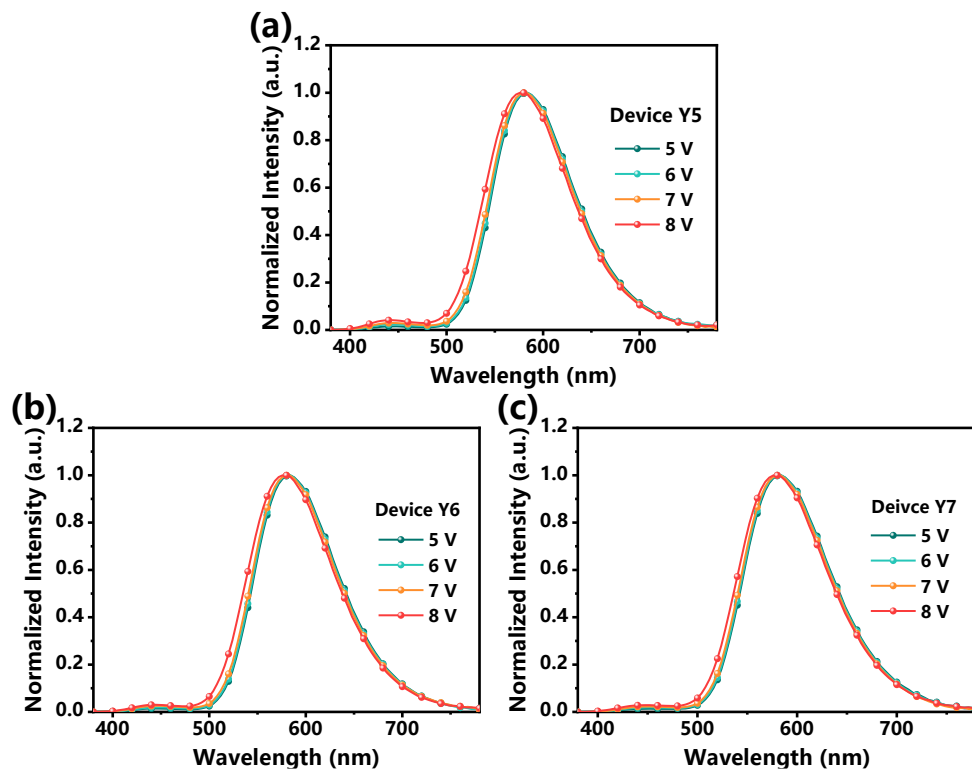


Figure S5. Normalized EL spectra for yellow devices Y5-Y7 at different driving voltages from 5 V to 8 V.

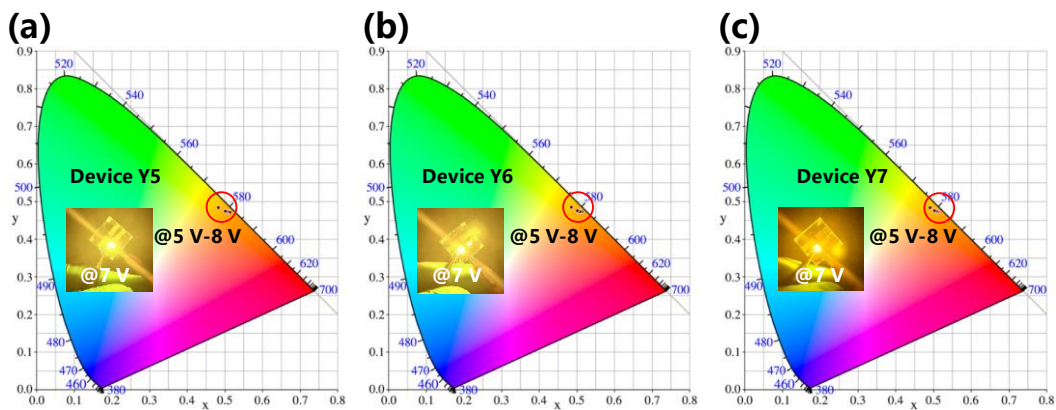


Figure S6. (a)-(c) CIE coordinates diagram of non-doped yellow devices Y5-7 at versus voltage and EL photo at 5 V.

V.

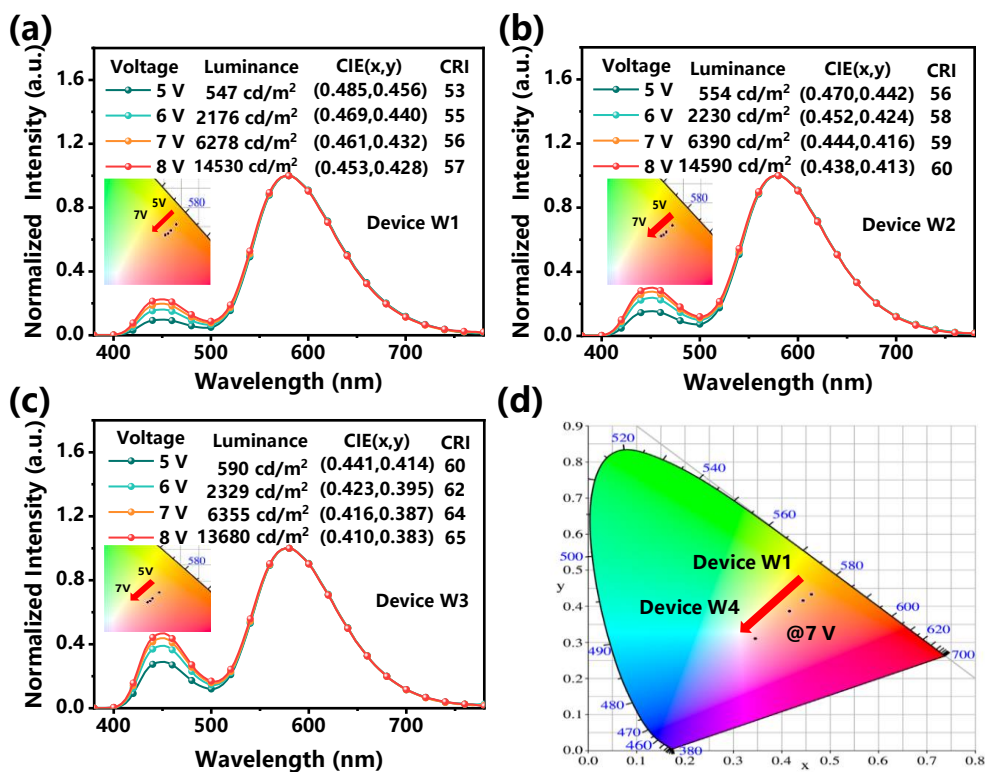


Figure S7. (a-c) Normalized EL spectra for white devices W1-W3 at different driving voltages from 5 V to 8 V;

(d) The CIE coordinate graph for white devices W1-W4 at a voltage of 7 V.

Table S1 Key performance parameters of the reported non-doped non-doped blue based-HLCT OLEDs exhibiting hot excitons process with $CIE \cong 0.08$.

Devices	CE(cd/A)	EQE (%)	λ_{EL} (cd/m ²)	CIE(x,y)	Ref.
pCzAnN	6.27	9.36	444	(0.151,0.068)	This work
TPATPA-CNPPi	19.58	8.96	457	(0.16,0.07)	[24]
SP	6.9	11.3	436	(0.158, 0.068)	[25]
SFCz	3.80	5.86	419	(0.16, 0.08)	[26]
SAFpCN	6.54	4.63	432	(0.153, 0.054)	[27]
SAF-PI	2.90	4.57	428	(0.156, 0.053)	[28]
IDCz-BPSP	5.81	4.61	432	(0.154,0.059)	[29]
PPITPh	7.21	11.83	436	(0.15, 0.07)	[30]
PCZPBO	2.8	5.1	414	(0.15,0.08)	[40]

Reference

24. J. Jayabharathi, S. Thilagavathy, V. Thanikachalam and J. Anudeebhana, *J. Mater. Chem. C.*, 2022, **10**, 4342-4354.
25. S. Xiao, Y. Gao, R. Wang, H. Liu, W. Li, C. Zhou, S. Xue, S. T. Zhang, B. Yang and Y. Ma, *Chem. Eng. J.*, 2022, **440**, 135911.
26. Y. Zhen, F. Zhang, H. Liu, Y. Yan, X. Li and S. Wang, *J. Mater. Chem. C.*, 2022, **10**, 9953-9960.
27. T. Sudyoasuk, S. Petdee, C. Kaiyasuan, C. Chaiwai, P. Wongkaew, S. Namuangruk, P. Chasinga and V. Promarak, *J. Mater. Chem. C.*, 2021, **9**, 6251-6256.
28. C. Kaiyasuan, P. Chasing, P. Nalaoh, P. Wongkaew, T. Suayoadsuk, K. Kongpatpanich and V. Promarak, *Chem. Asian. J.*, 2021, **16**, 2328-2337.
29. J. Wang, X. Zhai, C. Ji, M. Zhang, C. Yao, G. Xie, J. Zhang and X. Xi, *Dyes. Pigments.*, 2023, **219**, 111586.
30. C. Du, H. Liu, Z. Cheng, S. Zhang, Z. Qu, D. Yang, X. Qiao, Z. Zhao and P. Lu, *Adv. Funct. Mater.*, 2023, **33**, 2304854.
40. M. Xie, T. Li, C. Liu, C. Ma, S. Zhang, G. Liu, Q. Sun, S. T. Zhang, W. Yang and S. Xue, *Chem. Eng. J.*, 2023, **472**, 144950.

Table S2. The summary of the key EL performance for white devices W5-W8.

Devices	V_{on}^a (V)	CE^b (cd/A)	PE^b (lm/W)	L_{max} (cd/m²)	CIE^d (x,y)	CRI^e
W1	3.5	0.05	0.03	733.5	(0.440,0.426)	58/59
W2	3.9	0.09	0.04	1113	(0.426,0.392)	60/62
W3	4.2	0.12	0.05	1369	(0.415,0.361)	63/66
W4	4.8	0.13	0.05	1379	(0.413,0.346)	65/68

^a Turn-on voltage corresponds to the voltage at a luminance of >1 cd m⁻²;

^b maximum CE/PE;

^c CIE coordinates are measured at the voltage of 7 V;

^d CRI is measured at a voltage of 7 V and 8 V.